Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:
Glass and metal
Overall Length:
0.782 inches
Overall Diameter:
0.505 inches
Mounting Method:
Press fit
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
400.0 repetitive peak off-state voltage
Current Rating Per Characteristic:
10.00 amperes forward current, total rms horsepower metric
Power Rating Per Characteristic:
0.5 watts average gate power-forward
Maximum Operating Tempurature Per Measurement Point:
100.0 degrees celsius junction
Terminal Type And Quantity:
1 case and 2 tab, solder lug
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0